



5SDF 06D3004

Old part no. DM 827-620-30

Fast Recovery Diode

Properties

- § Optimized recovery characteristics
- § Industry standard housing

Applications

- § suited for GTO applications
- § Snubber diode
- § Freewheeling diode

Key Parameters

| | | | |
|------------|---|--------|----|
| V_{RRM} | = | 3 000 | V |
| I_{FAVm} | = | 615 | A |
| I_{FSM} | = | 10 000 | A |
| V_{TO} | = | 1.196 | V |
| r_T | = | 0.461 | mΩ |

Types

| | V_{RRM} |
|--|-----------|
| 5SDF 06D3004 | 3 000 V |
| 5SDF 06D2504 | 2 500 V |
| Conditions: $T_j = -40 \div 125$ °C, half sine waveform, $f = 50$ Hz | |

Mechanical Data

| | | |
|-------|---------------------------|-----------|
| F_m | Mounting force | 10 ± 2 kN |
| m | Weight | 0.27 kg |
| D_s | Surface creepage distance | 30 mm |
| D_a | Air strike distance | 20 mm |

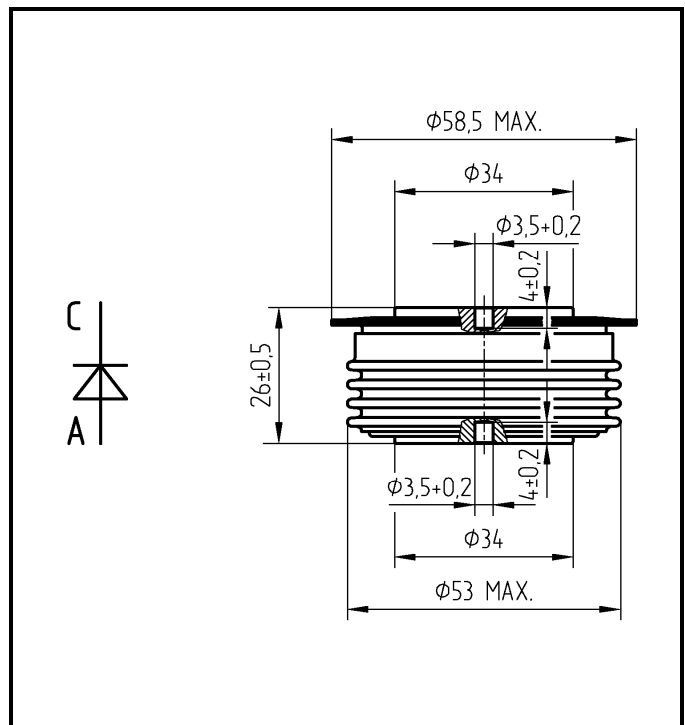


Fig. 1 Case



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| Maximum Ratings | | | Maximum Limits | Unit |
|------------------------|---|--|----------------------------------|------------------------------------|
| V_{RRM} | Repetitive peak reverse voltage $T_j = -40 \div 125 \text{ }^\circ\text{C}$ | 5SDF 06D3004 5SDF 06D2504 | 3 000 2 500 | V |
| I_{FAVm} | Average forward current $T_c = 85 \text{ }^\circ\text{C}$ | | 615 | A |
| I_{FRMS} | RMS forward current $T_c = 85 \text{ }^\circ\text{C}$ | | 966 | A |
| I_{RRM} | Repetitive reverse current $V_R = V_{RRM}$ | | 50 | mA |
| I_{FSM} | Non repetitive peak surge current $V_R = 0 \text{ V, half sine pulse}$ | $t_p = 8.3 \text{ ms}$ | 10 700 | A |
| | | $t_p = 10 \text{ ms}$ | 10 000 | A |
| $\int i^2 t$ | Limiting load integral $V_R = 0 \text{ V, half sine pulse}$ | $t_p = 8.3 \text{ ms}$ | 474 000 | A²s |
| | | $t_p = 10 \text{ ms}$ | 500 000 | A²s |
| $T_{jmin} - T_{jmax}$ | Operating temperature range | | -40 \div 125 | $^\circ\text{C}$ |
| T_{STG} | Storage temperature range | | -40 \div 125 | $^\circ\text{C}$ |

Unless otherwise specified $T_j = 125 \text{ }^\circ\text{C}$

| Characteristics | | Value | | | Unit |
|-----------------|--|-------|-----|-------|---------------|
| | | min | typ | max | |
| V_{T0} | Threshold voltage | | | 1.196 | V |
| r_T | Forward slope resistance $I_{F1} = 974 \text{ A}, I_{F2} = 2\,922 \text{ A}$ | | | 0.461 | mW |
| V_{FM} | Maximum forward voltage $I_{FM} = 1\,000 \text{ A}$ | | | 1.660 | V |
| Q_{rr} | Recovered charge $V_R = 100 \text{ V}, I_{FM} = 1000 \text{ A}, di/dt = -80 \text{ A}/\mu\text{s}$ | | 260 | 400 | μC |
| I_{rrM} | Reverse recovery maximum current <i>the same conditions as at Q_{rr}</i> | | 120 | 200 | A |
| t_{rr} | Reverse recovery time <i>the same conditions as at Q_{rr}</i> | | | 4.0 | μs |
| S | Soft factor, $S = t_s / t_f$ $I_{FM} = 1\,000 \text{ A}, di_f/dt = -200 \text{ A}/\mu\text{s}, V_R = 400 \text{ V}$ | | 2.0 | | - |
| I_{rrM} | Reverse recovery maximum current <i>the same conditions as at S</i> | | | 400 | A |
| V_{rrM} | Reverse recovery maximum voltage <i>the same conditions as at S</i> | | | 1 100 | V |

Unless otherwise specified $T_j = 125 \text{ }^\circ\text{C}$

| Thermal Parameters | | | Value | Unit |
|--------------------|-------------------------------------|----------------------|-------|------|
| R_{thjc} | Thermal resistance junction to case | double side cooling | 32 | K/kW |
| | | cathode side cooling | 50 | |
| | | anode side cooling | 88 | |
| R_{thch} | Thermal resistance case to heatsink | double side cooling | 8 | K/kW |
| | | single side cooling | 16 | |

| Transient Thermal Impedance | | | | | | | | | | | | | | |
|---|---|------------|----------|-------------------|----------|-------------------|----------|------------------|----------|--|--|--|--|--|
| Analytical function for transient thermal impedance $Z_{thjc} = \sum_{i=1}^5 R_i (1 - \exp(-t / \tau_i))$ | i | 1 | 2 | 3 | 4 | 5 | | | | | | | | |
| | τ_i (s) | 0.7033 | 0.2185 | 0.0588 | 0.0042 | 0.0006 | | | | | | | | |
| | R_i (K/kW) | 11.56 | 10.08 | 7.84 | 2.38 | 0.13 | | | | | | | | |
| Conditions: $F_m = 10 \pm 2$ kN, Double side cooled Correction for periodic waveforms | <table border="1"> <tr> <td>180° sine:</td> <td>2.3 K/kW</td> </tr> <tr> <td>180° rectangular:</td> <td>3.1 K/kW</td> </tr> <tr> <td>120° rectangular:</td> <td>5.1 K/kW</td> </tr> <tr> <td>60° rectangular:</td> <td>8.7 K/kW</td> </tr> </table> | 180° sine: | 2.3 K/kW | 180° rectangular: | 3.1 K/kW | 120° rectangular: | 5.1 K/kW | 60° rectangular: | 8.7 K/kW | | | | | |
| 180° sine: | 2.3 K/kW | | | | | | | | | | | | | |
| 180° rectangular: | 3.1 K/kW | | | | | | | | | | | | | |
| 120° rectangular: | 5.1 K/kW | | | | | | | | | | | | | |
| 60° rectangular: | 8.7 K/kW | | | | | | | | | | | | | |
| Fig. 2 Dependence transient thermal impedance junction to case on square pulse | | | | | | | | | | | | | | |

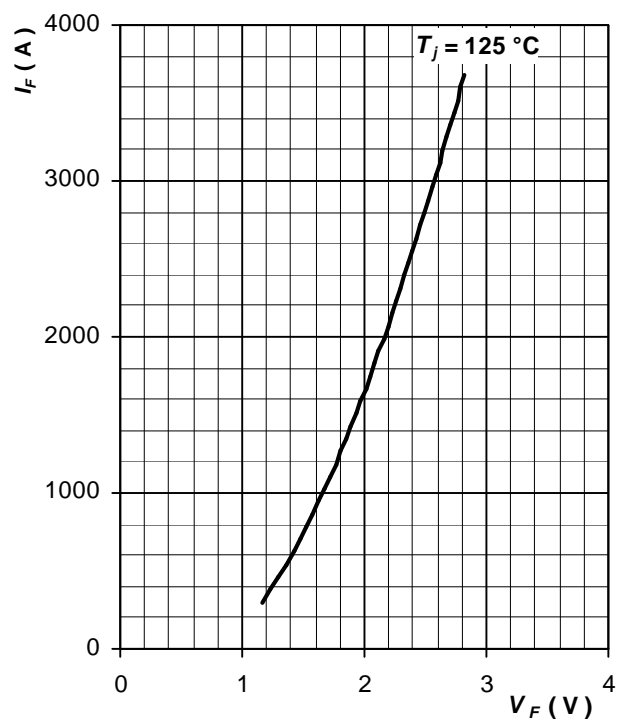
Forward Characteristics

Fig. 3 Maximum forward voltage drop characteristics

Surge Characteristics

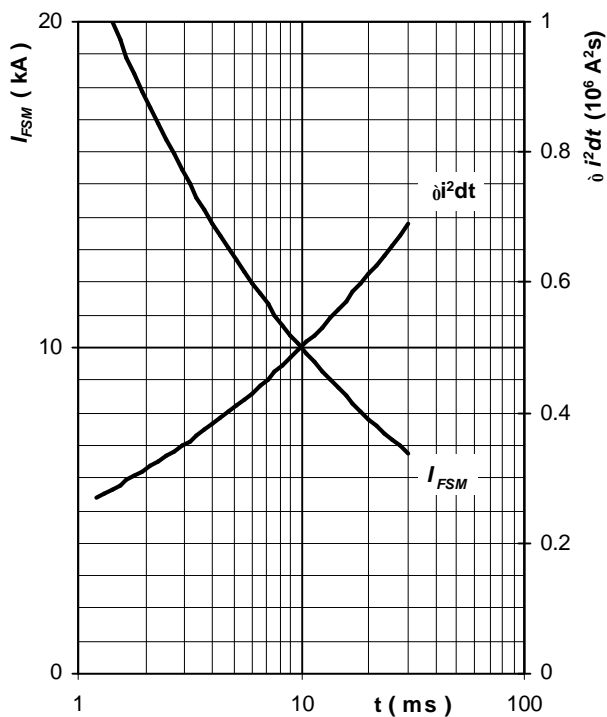


Fig. 4 Surge forward current vs. pulse length, half sine wave, single pulse, $V_R = 0$ V, $T_j = T_{jmax}$

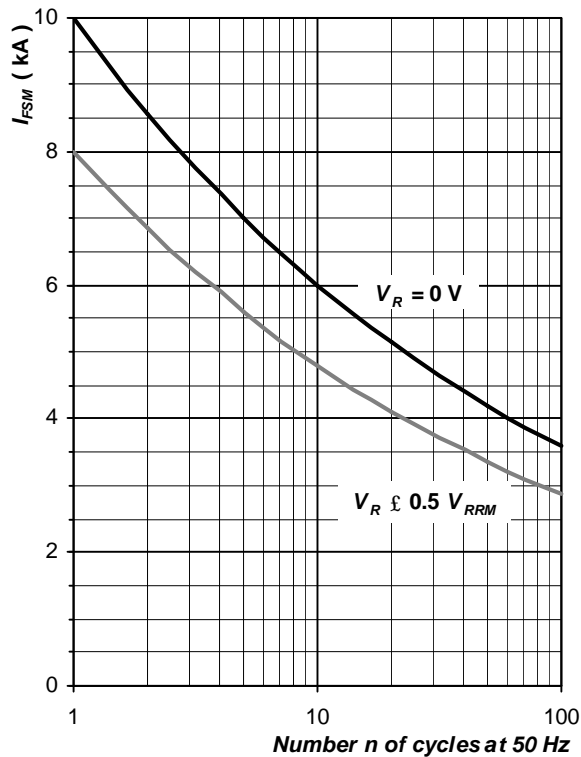


Fig. 5 Surge forward current vs. number of pulses, half sine wave, $T_j = T_{jmax}$

Power Loss and Maximum Case Temperature Characteristics

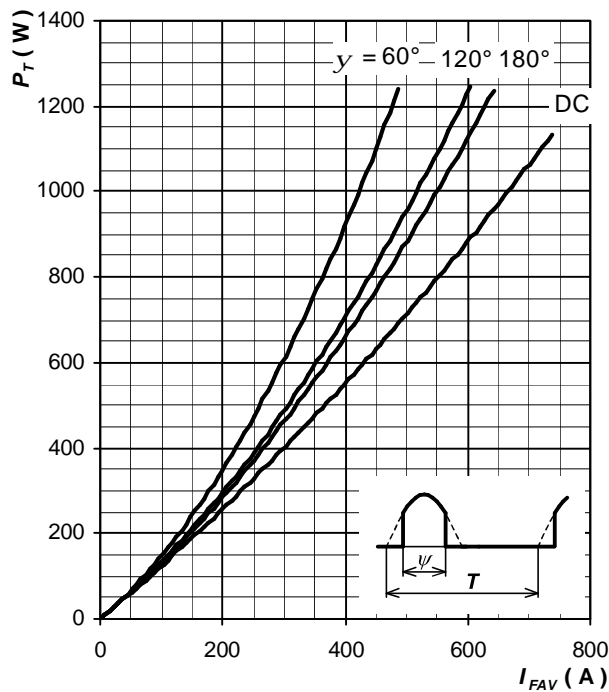


Fig. 6 Forward power loss vs. average forward current, sine waveform, $f = 50$ Hz, $T = 1/f$

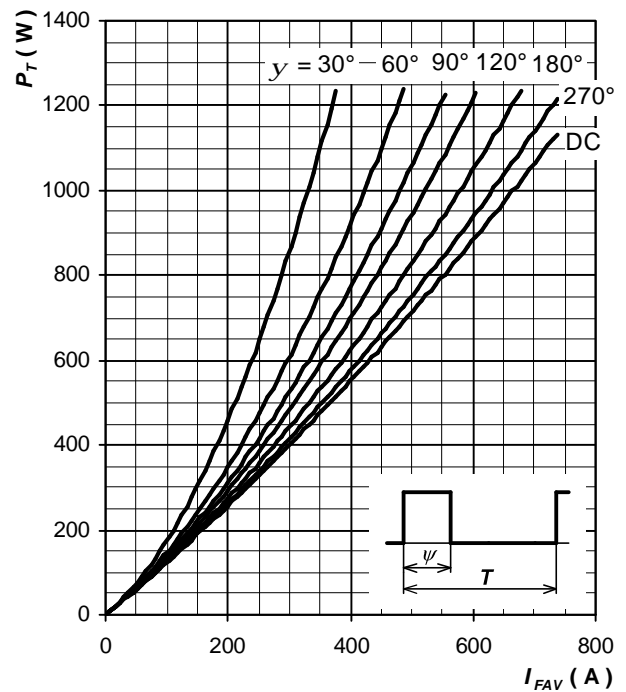


Fig. 7 Forward power loss vs. average forward current, square waveform, $f = 50$ Hz, $T = 1/f$

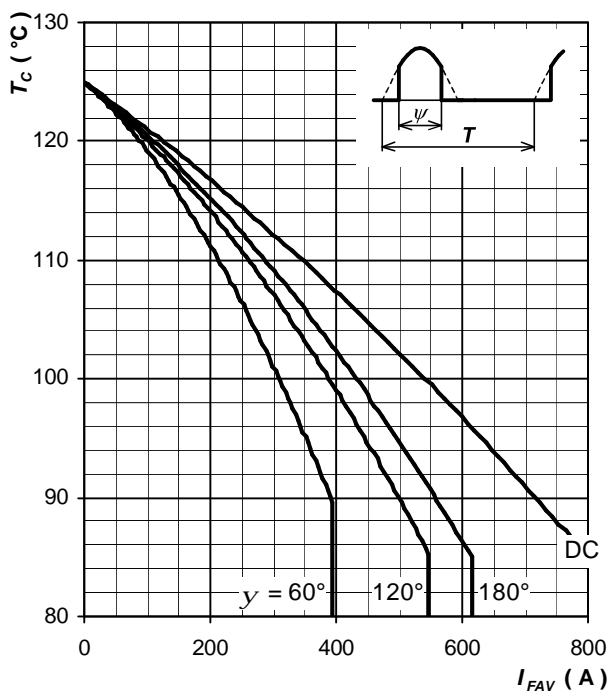


Fig. 8 Max. case temperature vs. aver. forward current, sine waveform, $f = 50$ Hz, $T = 1/f$

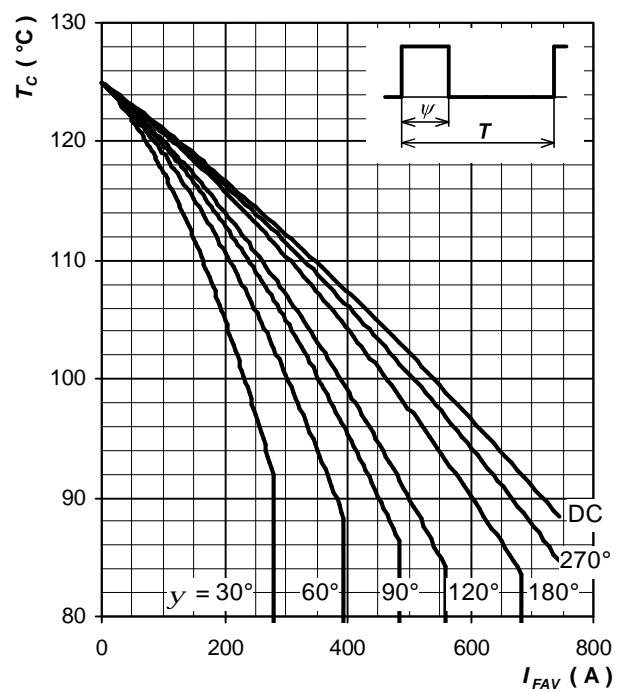


Fig. 9 Max. case temperature vs. aver. forward current, square waveform, $f = 50$ Hz, $T = 1/f$

Note 2: Figures number 6 , 9 have been calculated without considering any forward and reverse recovery losses. They are valid for $f = 50$ or 60 Hz operation.

Forward Recovery Characteristics

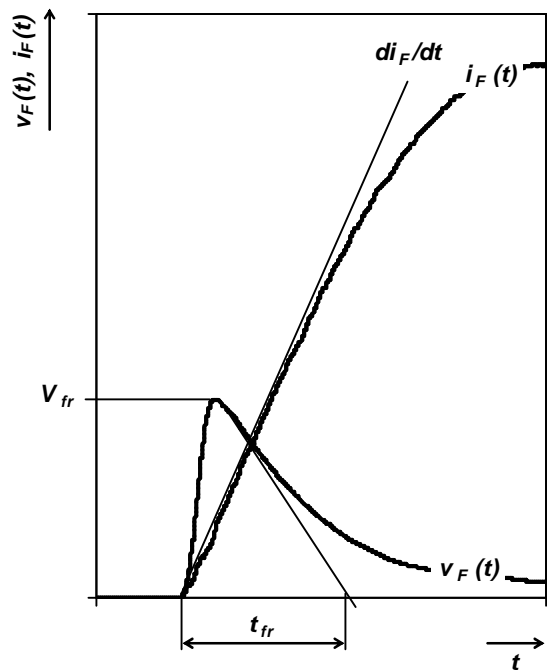


Fig. 10 Typical forward recovery voltage waveform when the diode is turned on with high di_F/dt

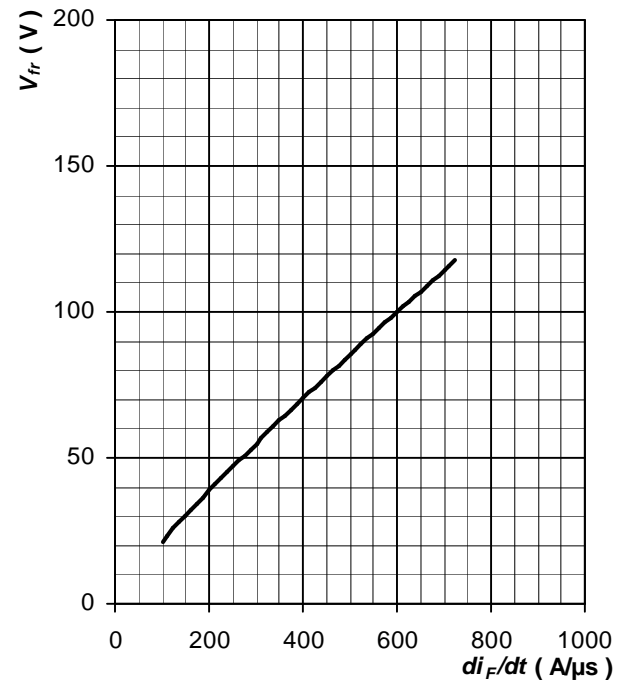


Fig. 11 Max. forward recovery voltage vs. rate of rise of forward current, trapezoid pulse, $T_j = T_{jmax}$, $t_{fr} \leq 10 \mu s$

Reverse Recovery Characteristics

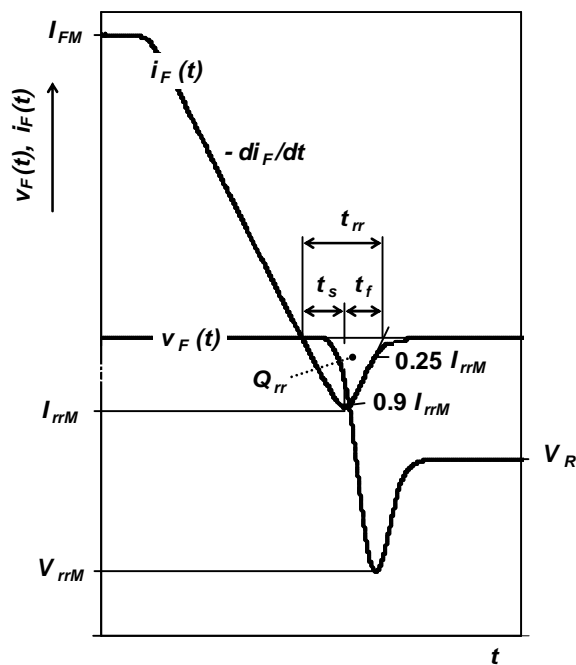


Fig. 12 Typical waveforms and definition of symbols at reverse recovery of a diode, inductive switching without RC snubber

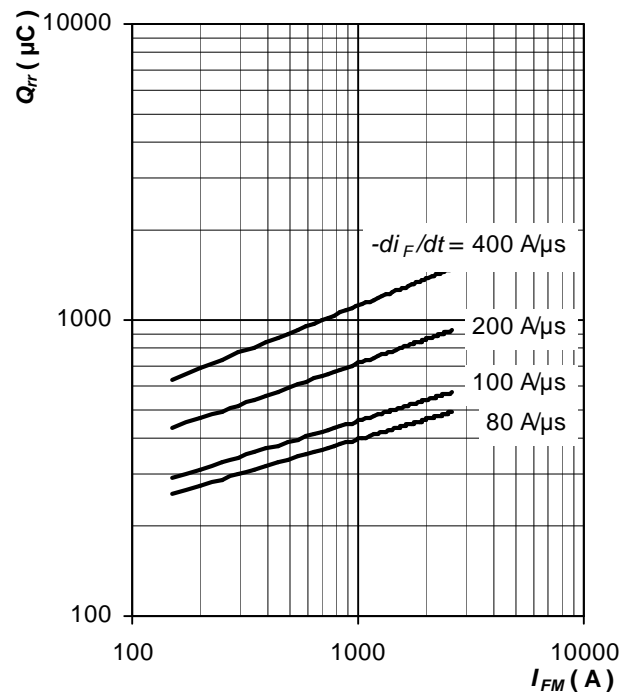


Fig. 13 Max. recovered charge vs. forward current, trapezoid pulse, $T_j = T_{jmax}$

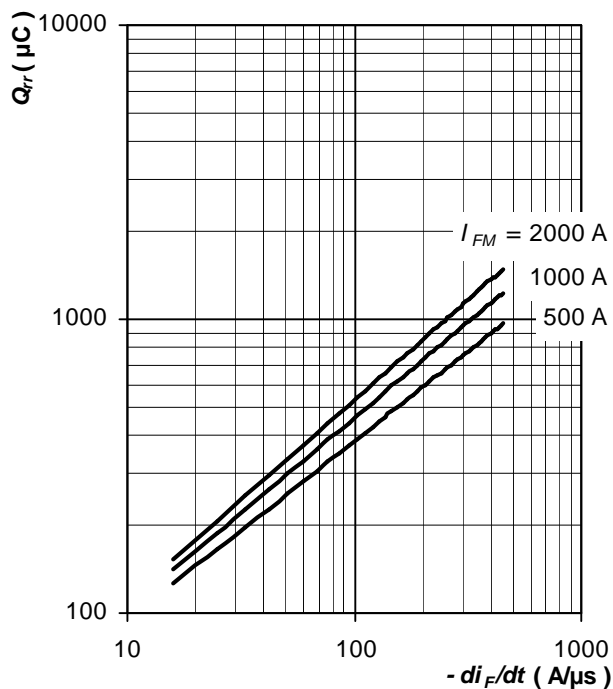


Fig. 14 Max. recovered charge vs. rate of fall of forward current, trapezoid pulse, $T_j = T_{jmax}$

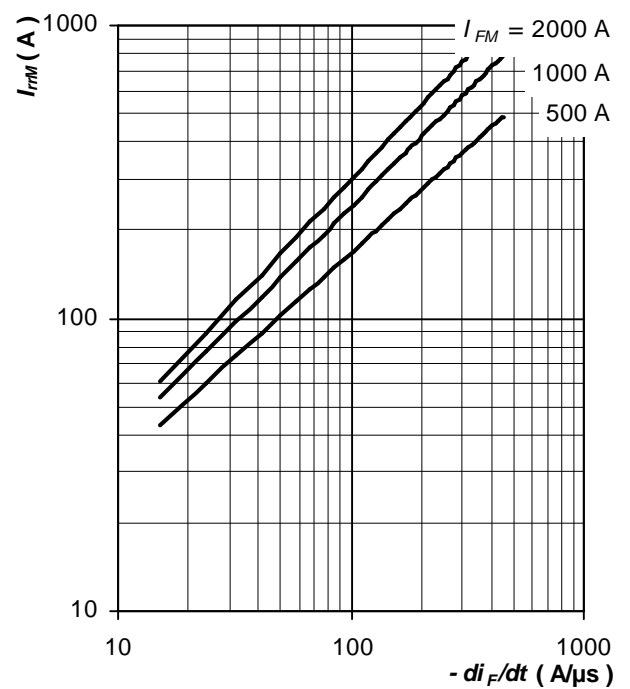


Fig. 15 Max. reverse recovery current vs. rate of fall of forward current, trapezoid pulse, $T_j = T_{jmax}$